

# OV8835 8-megapixel product brief





#### available in a lead-free package

## Best-In-Class Pixel Performance and High Frame Rate Photography for Smartphones and Tablets

The OV8835 leverages OmniVision's newly improved OmniBSI-2™ pixel architecture to deliver best-in-class pixel performance to next-generation smartphones and tablets. It is capable of capturing full resolution 8-megapixel high-speed photography at 30 frames per second (fps) or 1080p high definition (HD) video at 30 fps with electronic image stabilization (EIS) and 720p high-definition (HD) video at 60 fps.

The 1/3.2-inch OV8835 is built on an enhanced 1.4-micron OmniBSI-2 pixel that delivers dramatically improved sensitivity of  $1000 \, \text{mV/lux-sec}$ , a  $20 \, \text{percent}$  improvement over the previous generation OV8830. Other performance improvements over the previous generation 8-megapixel image sensor include a  $20 \, \text{percent}$  improvement in low-light performance and more than a  $25 \, \text{percent}$  improvement in full-well capacity.

The new CameraChip™ sensor supports an active array of 3264 x 2448 pixels (8-megapixel) operating at 30 fps for zero shutter lag. Its 2x2 binning functionality with post-binning resampling filter minimizes special artifacts and removes image artifacts around edges to deliver clean, crisp color image quality for industry-leading HD video recording.

The OV8835 fits into an industry standard  $8.5 \times 8.5$  module size and is pin-to-pin compatible with the previous generation OV8830.

Find out more at www.ovt.com.



#### **Applications**

- Cellular and Mobile Phones
- Digital Video Camcorders (DVC)
- Digital Still Cameras (DSC)
- PC Multimedia

#### **Product Features**

- automatic black level calibration (ABLC) up to 4-lane MIPI serial
- programmable controls for frame rate. mirror and flip, cropping, windowing, and scaling
- image quality controls: lens correction and defective pixel canceling
- supports output formats: 10-bit RAW RGB (MIPI)
- supports horizontal and vertical subsampling
- supports images sizes: 8MP, EIS1080p, 1080p, EIS720p, EISQ 1080p, Q1080p, EISVGA, VGA, QVGA, etc.
- fast mode switching
- support 2x2 binning, re-sampling filter
- standard serial SCCB interface

- output interface
- up to 4-lane LVDS serial output interface
- embedded 4K bits one-time programmable (OTP) memory for part identification, etc.
- three on-chip phase lock loops (PLLs)
- programmable I/O drive capability
- built-in 1.2V regulator for core
- built-in temperature sensor
- supports alternate row HDR timing
- supports ULPS and triggers in forward direction only

### OV8835



■ 0V08835-G04A

(color, chip probing, 200 µm backgrinding, reconstructed wafer with good die)

#### **Product Specifications**

- active array size: 3264 x 2448
- power supply:
  -core (for applications up to 30 fps):
  1.2-1.32V for up to 800 Mbps/lane
  -core (for applications up to 24 fps):
  1.14-1.32V for up to 800 Mbps/lane
  or 1.27-1.32V for up to 1 Gbps/lane
  -analog: 2.6-3.0V
  -I/O: 1.7-3.0V
- power requirements:
   active (for up to 30 fps):
  152 mA (265 mW), if the internal regulator is used, a higher power consumption 316 mW with DOVDD = 1.8V is achieved
- DOVDD = 1.8V is achieved active (for up to 24 fps): 132 mA (235 mW), if the internal regulator is used, a higher power consumption 280 mW with DOVDD = 1.8V is achieved standby: 300 µA XSHUTDOWN: 10 µA
- temperature range:
- operating (for applications up to 30 fps):

  0°C to 70°C junction temperature

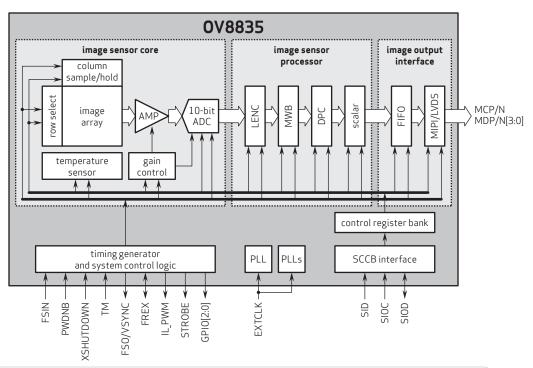
  operating (for applications up to 24 fps):

  -30°C to 70°C junction temperature
- stable image: 0°C to 50°C junction temperature

- output formats: 10-bit RAW RGB data
- lens size: 1/3.2"
- lens chief ray angle: 27° non-linear
- input clock frequency: 6 27 MHz
- max S/N ratio: 36.6 dB
- dynamic range: 68.7 dB @ 8x gain
- maximum image transfer rate:
  -8MP: 30 fps
   EIS1080p: 30 fps
   EIS720p: 60 fps

- sensitivity: 824 mV/lux-sec
- scan mode: progressive
- maximum exposure interval: 2480 x t<sub>ROW</sub>
- pixel size: 1.4 µm x 1.4 µm
- dark current: 10 e<sup>-</sup>/s @ 50°C junction temperature
- image area: 4592 µm x 3450 µm
- die dimensions: 6410 µm x 5940 µm

### Functional Block Diagram



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